Vishay General Semiconductor

High Current Density Surface-Mount Ultrafast Rectifiers



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Cathode O Anode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2.0 A			
V _{RRM}	100 V, 150 V, 200 V			
I _{FSM}	50 A			
t _{rr}	25 ns			
V_F at $I_F = 2 A$	0.75 V			
T _J max.	175 °C			
Package	SMP (DO-220AA)			
Circuit configuration	Single			

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Glass passivated pellet chip junction
- Ultrafast recovery times for high frequency
- Low forward voltage drop, low power losses
- · Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of AC/DC and DC/DC converters in high temperature for both consumer and automotive applications.

MECHANICAL DATA

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and automotive grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT	
Device marking code		P2B	P2C	P2D		
Maximum repetitive peak reverse voltage	V _{RRM}	100 150 200		200	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	2.0			Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50			А	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	



RoHS COMPLIANT HALOGEN

FREE

Available





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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous	I _F = 2 A	T _J = 25 °C	V _F (1)	0.90	0.98	V	
forward voltage	$I_F = 2 A$	T _J = 125 °C	VF	0.75	0.82	v	
Maximum reverse current at		T _J = 25 °C	I _B ⁽²⁾	0.2	1.0	μA	
rated V _R		$T_J = 125 \text{ °C}$	'R (-/	12.6	25		
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	-	25	ns	
Typical reverse recovery time	I _F = 1.0 A, V _R = 30 V,	T _J = 25 °C	t _{rr}	25	-	ns	
	dl/dt = 50 A/ μ s, I _{rr} = 10 % I _{RM}	$T_J = 100 \ ^\circ C$		35	-		
Typical stored charge	I _F = 1.0 A, V _R = 30 V,	T _J = 25 °C	Q _{rr}	10	-	nC	
	dI/dt = 50 A/ μ s, I _{rr} = 10 % I _{RM}	$T_J = 100 \ ^\circ C$		15	-		
Typical junction capacitance	4.0 V, 1 MHz		CJ	25	-	pF	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT	
Typical thermal resistance	R _{0JA} ⁽¹⁾	80			°C/W	
	R _{0JL} ⁽¹⁾	15				
	R _{θJC} ⁽¹⁾		22			

Note

⁽¹⁾ Thermal resistance from junction to ambient and junction to lead mounted on PCB with 6.0 mm x 6.0 mm copper pad areas. R_{θJL} is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
ESH2PBHM3/84A ⁽¹⁾	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PBHM3/85A ⁽¹⁾	0.024	85A	10 000	13" diameter plastic tape and reel		

Note

⁽¹⁾ Automotive grade



ESH2PB, ESH2PC, ESH2PD

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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

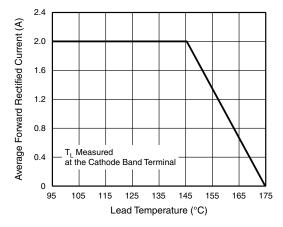


Fig. 1 - Maximum Forward Current Derating Curve

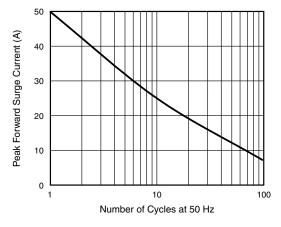


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

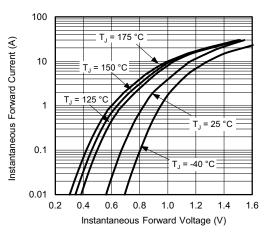


Fig. 3 - Typical Instantaneous Forward Characteristics

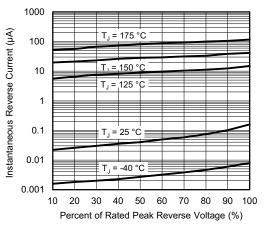


Fig. 4 - Typical Reverse Leakage Characteristics

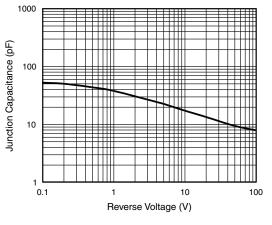


Fig. 5 - Typical Junction Capacitance

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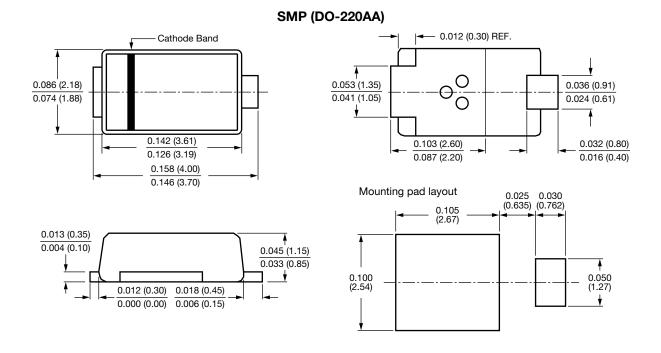
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ESH2PB, ESH2PC, ESH2PD

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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